8. Estados electrónicos



Overlap of atomic states



Bands



Electronic energy along a line of atoms



Bloch's theorem

we can rewrite the Bloch theorem equation $\psi(x+a) = \exp(ika)\psi(x)$ alternative form

 $\psi(x) = u(x)\exp(ikx)$

where u(x) is periodic with the lattice periodicity.



Concept of the Bloch functions. We can think of the exp(ikx) as being an example of an "envelope" function that multiplies the unit cell function u(x)

Bloch function



Bloch functions



Bands of copper in the 100 direction



Band overlap



Recall: Covalent Bonding



Bonding and anti-bonding states & energies



Many atoms: bands



Exercise: tight binding model in 1d



Simon, S. H. (2013). The Oxford solid state basics. Oxford, UK: Oxford Univ. Press.

Free electron bands in 1d



Bragg reflection of free electrons



Band gaps of nearly free electrons in 1d



Nearly free electron bands in 1d



FIGURE 7-7 Energy as a function of propagation vector magnitude for nearly free electrons. The propagation vector is taken to be parallel to reciprocal lattice vector G_1 , which is bisected by a Brillouin zone boundary. The curves are similar to those of Fig. 7-6b but gaps occur at $\mathbf{k} = \pm \frac{1}{2}G_1$. The gap width depends on the Fourier component $U(G_1)$ of the potential energy function.

Brillouin zones in 2d



Nearly free electron bands in 2d



Free electron bands in 3d: Al



Nearly free electron bands In 3d: Al



Bands of potassium in 3 directions



FIGURE 7-8 Electron band structure of potassium for energies near the 4s atomic level: (a) **k** in the [100] direction; (b) **k** in the [110] direction; and (c) **k** in the [111] direction. Some curves are incomplete. The bands shown are quite similar in form to those predicted by the nearly free electron model. (From F. S. Ham, *Phys. Rev.* **128**:82, 1962. Used with permission.)

Bands of silicon in 3 directions



FIGURE 7-9 Electron band structure of crystalline silicon for energies near the 3s and 3p atomic levels: (a) k in the [100] direction; (b) k in the [110] direction; and (c) k in the [111] direction. Bands below E = 0 are valence bands and are associated with bonding. Higher bands are conduction bands and are important for the electrical properties of silicon. A gap exists between the valence and conduction bands. (From A. Zunger and M. L. Cohen, *Phys. Rev.* **B** 20:4082, 1979. Used with permission.)

9. Termodinâmica de electrões





Fermi level



Density of states



Fermi surface of free electrons in 2d (square)



Fermi surface of nearly free electrons in 2d (square)



BZ of the square lattice: electrons & holes



BZ of the rectangular lattice: electrons & holes



BZ of the face centred rectangular lattice: electrons & holes



BZ of the hexagonal lattice: electrons & holes



BZ of the oblique lattice: electrons & holes



Fermi surface of alkali (bcc) and noble (fcc) metals of valence 1



Fermi surface of Cu (fcc valence 1)



Fermi surface in 3d of Al (fcc valence 3)



Fcc lattice



Bcc lattice



Hexagonal lattice



3rd & 4th BANDS

5th & 6th BANDS







VALENCE I







VALENCE 3

Fermi-Dirac distribution



Electronic specific heat

$$C_{electrons} = \frac{\pi^2 N_A k^2 T}{2E_F} mole^{-1}$$

Specific heat of solids



